







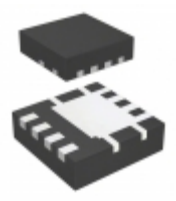

	<h2 style="color: red;">DMT6005LPS-13</h2>	
	Hersteller-Teilenummer:	DMT6005LPS-13
	Hersteller / Marke:	Diodes Incorporated
	Teil der Beschreibung:	MOSFET N-CHA 60V 17.9A POWERDI
Datenblätter:	 DMT6005LPS-13.pdf	
RoHs Status:	Bleifrei / RoHS-konform	
Lagerzustand:	New original, 16521 pcs Stock Available.	
Liefern von:	Hong Kong	
Versandweg:	DHL/Fedex/TNT/UPS/EMS	
Image may be representation. See specs for product details.		

Spezifikationen

Teilenummer	DMT6005LPS-13
Hersteller	Diodes Incorporated
Beschreibung	MOSFET N-CHA 60V 17.9A POWERDI
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	16521 pcs Stock
Serie	Automotive, AEC-Q101
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	8-PowerTDFN
Supplier Device-Gehäuse	PowerDI5060-8
Verlustleistung (max)	2.6W (Ta), 125W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	60V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	17.9A (Ta), 100A (Tc)
Rds On (Max) @ Id, Vgs	4.9 mOhm @ 50A, 10V
VGS (th) (Max) @ Id	3V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	47.1nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	2962pF @ 30V
Antriebsspannung (Max Rds On, Min Rds On)	4.5V, 10V
Vgs (Max)	±20V
Verpackung	Tape & Reel (TR)



















































DMT6005LPS-13 ist neu im Original, Suche DMT6005LPS-13 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie DMT6005LPS-13 Diodes Incorporated mit Garantie und Vertrauen. Anfrage DMT6005LPS-13: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>DMT6004SCT Diodes Incorporated MOSFET N-CH 60V 100A TO220-3</p>	 <p>DMT6005LSS Diodes Incorporated DMT6005LSS DIODES</p>	 <p>DMT6004SPS-13 Diodes Incorporated MOSFET N-CH 60V 23A POWERDI5060</p>	 <p>DMT6005LSS-13 Diodes Incorporated MOSFET N-CHA 60V 13.5A SO8</p>
 <p>DMT6004SPS Diodes Incorporated DMT6004SPS DIODES</p>	 <p>DMT6005LPS Diodes Incorporated DMT6005LPS DIODES</p>	 <p>DMT6007LFG-7 Diodes Incorporated MOSFET BVDSS: 41V 60V POWERDI333</p>	 <p>DMT6005LCT Diodes Incorporated MOSFET NCH 60V 100A TO220AB</p>

heiße Teile

Mehr

 DMT10H025SSS	 DMT3001LPS	 DMT3002LPS-13	 DMT3003LFG-13	 DMT3003LFG-7
 DMT3004LFG-13	 DMT3004LPS-13	 DMT3006LFG-13	 DMT3006LFV	 DMT3006LPS-13
 DMT3009LDT	 DMT3009LDT-13	 DMT3009LDT-7	 DMT3009LFVW	 DMT3009LFVW-13
 DMT3009LFVW-7	 DMT3020LPS	 DMT3020LSD	 DMT32M5LPS	 DMT4011LFG-7
 DMT40M9LPS-13	 DMT6004LPS-13	 DMT6004SPS	 DMT6004SPS-13	 DMT6005LPS
 DMT6005LSS	 DMT6008LFG	 DMT6008LFG-7	 DMT6009LCT	 DMT6009LFG
 DMT6009LFG-13	 DMT6009LK3	 DMT6009LPS	 DMT6009LPS-13	 DMT6009LSS
 DMT6010LFG	 DMT6010LFG-13	 DMT6010LFG-7	 DMT6010LPS-13	 DMT6010LSS
 DMT6010LSS-13	 DMT6010SCT	 DMT6015LFV	 DMT6015LFV-13	 DMT6015LFV-7
 DMT6015LPS-13	 DMT6015LSS	 DMT6015LSS-13	 DMT6016LSS	 DMT6016LSS-13

Contact us: Info@Y-IC.com

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